

## Features

- Insertion Loss: <3 dB
- Return Loss (at all conditions): >10 dB
- Wide Attenuation range: >25 dB
- P1dB: 25 dBm
- Control Voltage: -5.0 V to +1.4 V
- Die Size: 1.33 x 0.93 x 0.10 mm

## Applications

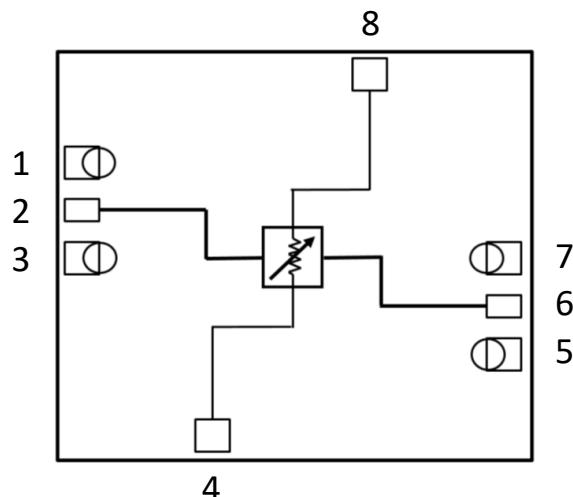
- MMW Radios
- Automotive Radar
- Radiometry
- Passive Imaging
- SATCOM
- MMW Test Equipment.

## Description

The MAAV-011014-DIE is a wide band PIN Diode Voltage-Variable Attenuator (VVA). This device is designed and manufactured utilizing MACOM's AlGaAs PIN diode technology which is ideally suited for high frequency, high linearity, and high power applications.

This MAAV-011014 VVA exhibits the lowest insertion loss, and the highest P1dB available for this frequency band.

## Functional Schematic



## Pin Configuration<sup>1,2</sup>

Pin #	Function	Description
1, 3, 5, 7	GND	Ground <sup>1</sup>
2	RF_IN	RF Input
4, 8	V_Control	Bias Control <sup>2</sup>
6	RF_OUT	RF Output

1. Connects to back side GND thru a substrate via
2. Pin 4 and pin 8 are DC connected. Do not use both at the same time.

## Ordering Information

Part Number	Package
MAAV-011014-DIE	Waffle Pack

\*Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

**Electrical Specifications:**

**Freq. = 80 - 100 GHz,  $T_A = 25^\circ\text{C}$ ,  $Z_0 = 50 \Omega$ ,  $V_{\text{CONTROL}}^3 = -5 \text{ V to } +1.4 \text{ V}$ ,  $P_{\text{IN}} = 0 \text{ dBm}$**

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Reference Insertion Loss	—	dB	—	-3.5	—
Attenuation Range <sup>3</sup>	—	dB	—	35	—
Return Loss (In/Out)	All attenuation conditions	dB	—	10	—
Input P1dB	Insertion loss state	dBm	—	25	—
IIP <sub>3</sub>	2-Tone, +10 dBm/tone, 1 MHz Spacing	dBm	—	40	—

3. Refer to the transfer curve on page 3 for attenuation vs current (or voltage) settings.

**Absolute Maximum Ratings<sup>4,5</sup>**

Parameter	Absolute Maximum
Input power	29 dBm
Control voltage	$-5.5 \text{ V} \leq V_{\text{Control}} \leq 1.5 \text{ V}$
Control current	20 mA
Junction Temperature	+150°C
Operating Temperature	-55°C to +85°C
Storage Temperature	-65°C to +150°C

4. Exceeding any one or combination of these limits may cause permanent damage to this device.  
 5. MACOM does not recommend sustained operation near these survivability limits.

**Static Sensitivity**

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HMB Class 1A devices.

**Solder Die Attach**

All die attach and bonding methods should be compatible with gold. Solder which does not scavenge gold, such as 80 Au/20 Sn or Indalloy #2, is recommended. Do not expose die to a temperature greater than 300°C for more than 10 seconds.

**Electrically Conductive Epoxy  
Die Attach**

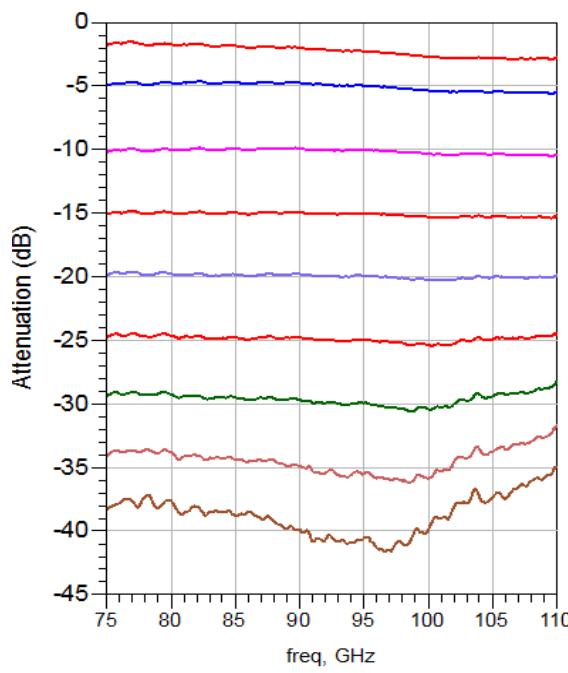
Assembly can be preheated to approximately 125°C. Use a controlled thickness of approximately 1 mils for best electrical conductivity and lower thermal resistance. A thin epoxy fillet should be visible around the perimeter of the chip after placement. Cure epoxy per manufacturer's schedule. For extended cure times, temperatures should be kept below 150°C.

**Wire / Ribbon Bonding**

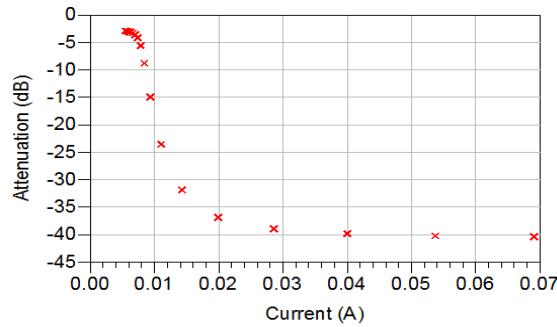
Wedge thermo compression bonding may be used to attach ribbons to the RF bonding pads. Gold ribbons should be at least 1/4 by 2 mil for lowest inductance. The same gold ribbon or 1 mil dia. gold wire is recommended for all DC pads.

## Typical Performance Curves

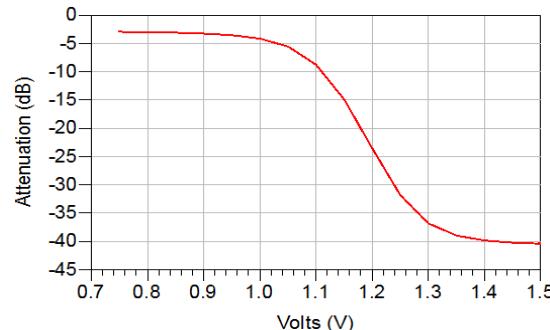
Typical Attenuation Dynamic Range (raw)



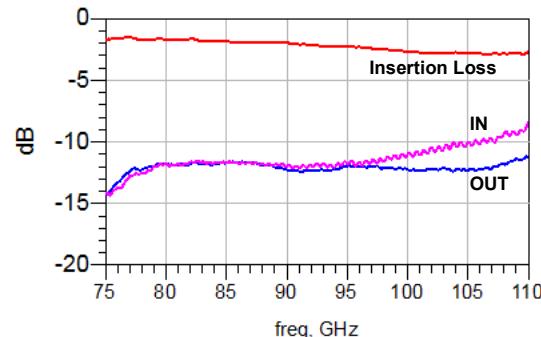
Typical Attenuation VS Control Current



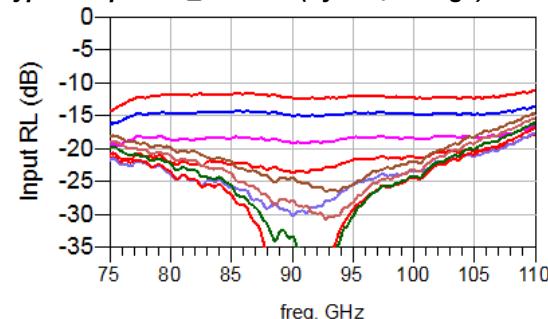
Typical Attenuation VS Control Voltage



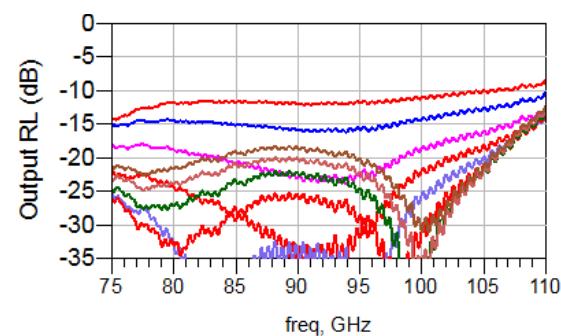
Typical reference I. Loss, & Return Loss (IN/OUT)



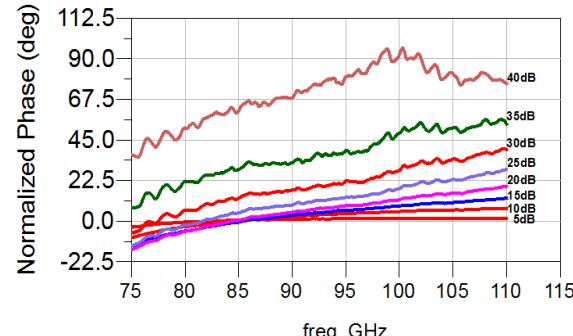
Typical Input Return Loss (dynamic range)



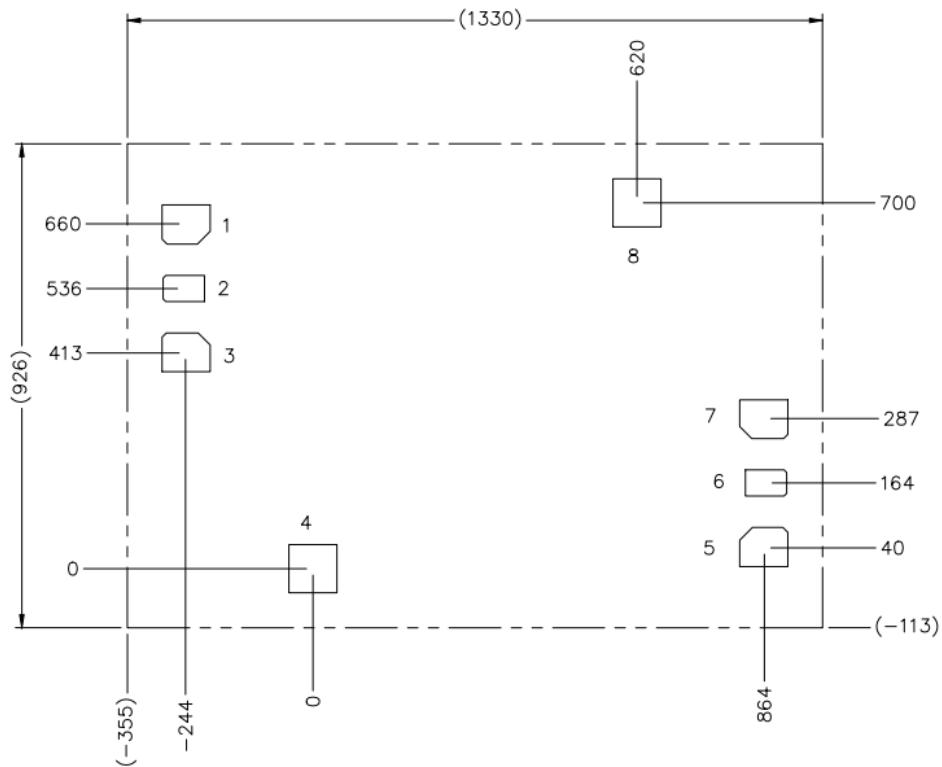
Typical Output Return Loss (dynamic range)



Normalized Phase response (dynamic range)



**Outline Drawing**



BOND PAD DIM ( $\mu$ m)		
PAD	X	Y
1,3,5,7	92	81
2,6	79	50
4,8	92	92

NOTES:

1. UNLESS OTHERWISE SPECIFIED, ALL DIMENSIONS SHOWN ARE  $\mu$ m WITH A TOLERANCE OF  $\pm 5 \mu$ m.
2. DIE THICKNESS IS 100  $\pm$  10  $\mu$ m
3. BOND PAD/BACKSIDE METALIZATION: GOLD.
4. DIE SIZE REFLECTS UN-CUT DIMENSIONS. SAW OR LASER KERF REDUCES DIE SIZE BY  $\sim 25 \mu$ m EACH DIMENSION.

MACOM Technology Solutions Inc. ("MACOM"). All rights reserved.

These materials are provided in connection with MACOM's products as a service to its customers and may be used for informational purposes only. Except as provided in its Terms and Conditions of Sale or any separate agreement, MACOM assumes no liability or responsibility whatsoever, including for (i) errors or omissions in these materials; (ii) failure to update these materials; or (iii) conflicts or incompatibilities arising from future changes to specifications and product descriptions, which MACOM may make at any time, without notice. These materials grant no license, express or implied, to any intellectual property rights.

THESE MATERIALS ARE PROVIDED "AS IS" WITH NO WARRANTY OR LIABILITY, EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHT, ACCURACY OR COMPLETENESS, OR SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES WHICH MAY RESULT FROM USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.